Device Modeling Report

COMPONENTS: Light-Emitting Diode (LED) Professional

PART NUMBER: OSWT5111A

MANUFACTURER: OPTO SUPPLY

REMARK: - 40 degree C

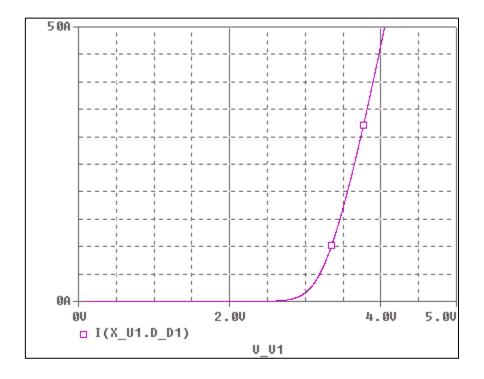


Bee Technologies Inc.

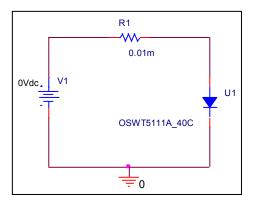
PSpice model parameter	Model description		
IS	Saturation Current		
N	Emission Coefficient		
RS	Series Resistance		
IKF	High-injection Knee Current		
CJO	Zero-bias Junction Capacitance		
M	Junction Grading Coefficient		
VJ	Junction Potential		
ISR	Recombination Current Saturation Value		
BV	Reverse Breakdown Voltage(a positive value)		
IBV	Reverse Breakdown Current(a positive value)		
TT	Transit Time		
EG	Energy-band Gap		

Forward Current Characteristic

Circuit Simulation Result

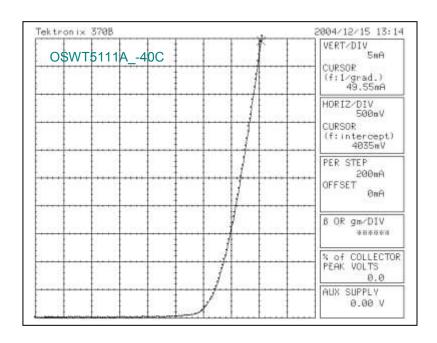


Evaluation Circuit



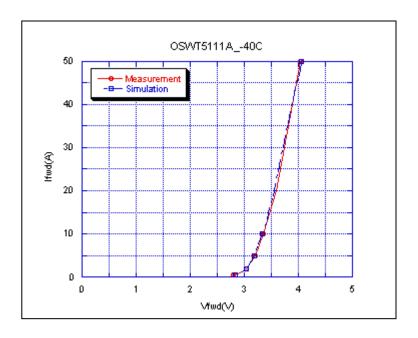
Forward Current Characteristic

Reference



Comparison Graph

Circuit Simulation Result

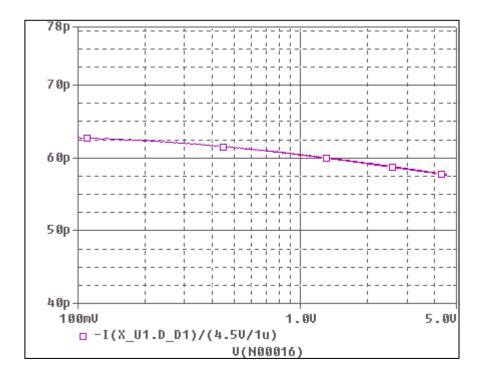


Simulation Result

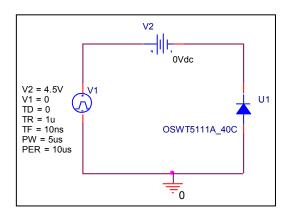
	Vfwd(V)	Vfwd(V)	
Ifwd(A)	Measurement	Simulation	%Error
0.5	2.8	2.838	1.3571
1	2.93	2.933	0.1023
2	3.035	3.035	0
5	3.21	3.191	0.5919
10	3.355	3.343	0.3576
20	3.585	3.557	0.7810
50	4.035	4.05	0.3717

Capacitance Characteristic

Circuit Simulation Result

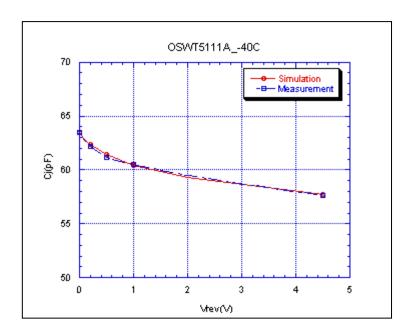


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

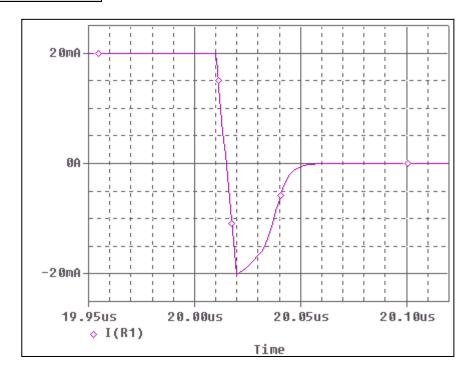


Simulation Result

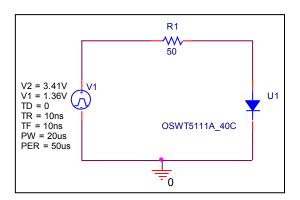
	Cj(pF)	Cj(pF)	
Vrev(V)	Measurement	Simulation	%Error
0	63.5	63.5	0
0.1	62.85	62.73	0.19093
0.2	62.15	62.39	0.38616
0.5	61.2	61.39	0.31045
1	60.5	60.45	0.08264
2	59.48	59.28	0.33624
4.5	57.6	57.76	0.27777

Reverse Recovery Characteristic

Circuit Simulation Result

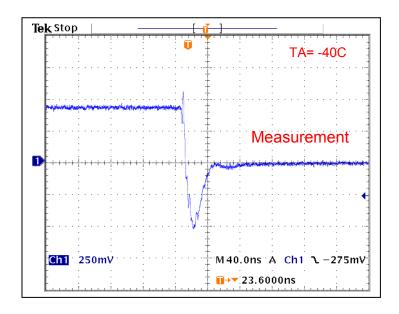


Evaluation Circuit



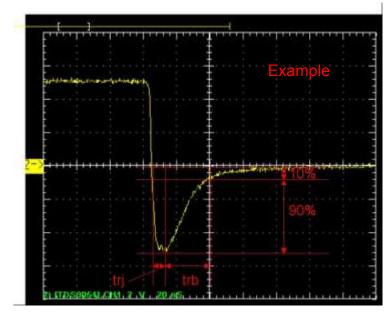
Compare Measurement vs. Simulation

Symbol	Measurement	Unit	Simulation	Unit	%Error
trj	8.8	ns	8.82	ns	0.22727
trb	20.8	ns	20.7	ns	0.48076



Trj =8.8(ns) Trb=20.8(ns)

Conditions: Ifwd=Irev=0.02(A), RI=50



Relation between trj and trb